Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

## SSM6P15FU

High Speed Switching Applications Analog Switch Applications

Small package

• Low ON resistance :  $R_{on} = 12 \Omega \text{ (max) } (@V_{GS} = -4 \text{ V})$ 

:  $R_{on} = 32 \Omega \text{ (max) } (@V_{GS} = -2.5 \text{ V})$ 

# Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DS</sub>	-30	V	
Gate-Source voltage		V <sub>GSS</sub>	±20	٧	
Drain current	DC	I <sub>D</sub>	-100	mA	
	Pulse	I <sub>DP</sub>	-200		
Drain power dissipation (Ta = 25°C)		P <sub>D</sub> (Note 1)	200	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating.

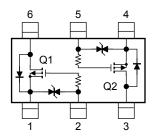
# 1: Source1 2: Gate1 3: Drain2 4: Source2 US6 5: Gate2 6: Drain1 JEDEC JEITA TOSHIBA 2-2J1C

Weight: 0.0068g(typ.)

### Marking

# 6 5 4 D Q

### **Equivalent Circuit (top view)**



### **Handling Precaution**

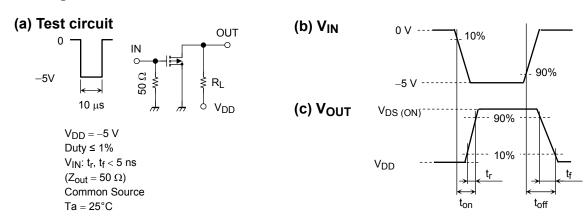
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Start of commercial production 2002-03

### Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT	
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μА	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-30	_	_	V	
Drain cut-off current		I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	_	_	-1	μΑ	
Gate threshold voltage		$V_{th}$	$V_{DS} = -3 \text{ V}, I_D = -0.1 \text{ mA}$	-1.1	_	-1.7	V	
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$	20	_	_	mS	
Drain-Source ON resistance		R <sub>DS</sub> (ON)	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$	_	8	12	Ω	
			$I_D = -1 \text{ mA}, V_{GS} = -2.5 \text{ V}$	_	14	32	22	
Input capacitance		C <sub>iss</sub>		_	9.1	_	pF	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.5	_	pF	
Output capacitance		Coss		_	8.6	_	pF	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = -5 \text{ V}, I_D = -10 \text{ mA},$	_	65	_	ns	
	Turn-off time	t <sub>off</sub>	$V_{GS} = 0 \text{ to } -5 \text{ V}$	_	175	_		

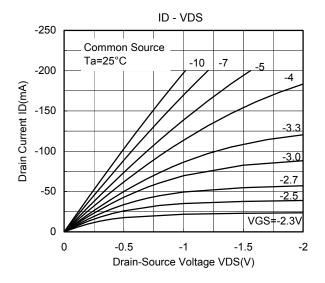
### **Switching Time Test Circuit**

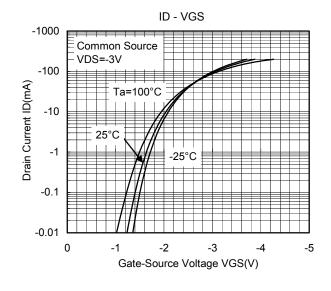


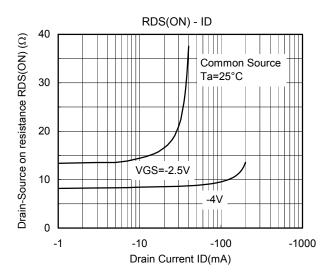
### **Precaution**

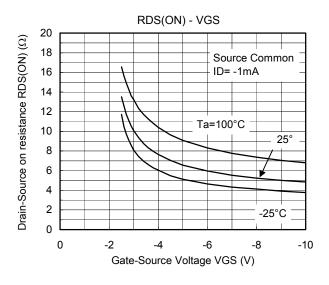
 $V_{th}$  can be expressed as voltage between gate and source when low operating current value is  $I_D=-100~\mu A$  for this product. For normal switching operation,  $V_{GS~(on)}$  requires higher voltage than  $V_{th}$  and  $V_{GS~(off)}$  requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS~(off)} < V_{th} < V_{GS~(on)}$ )

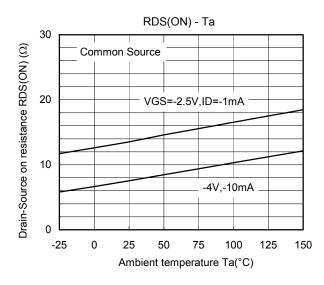
Please take this into consideration for using the device.

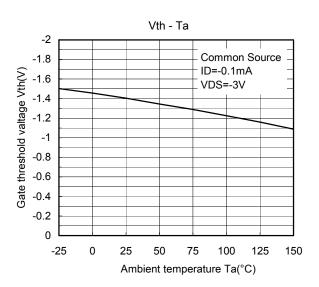


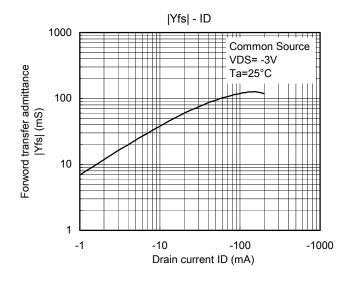


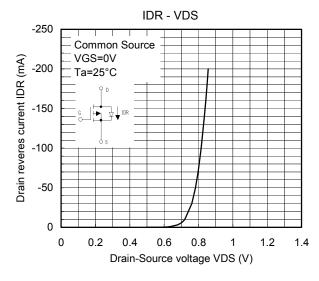


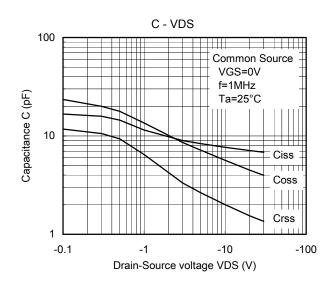


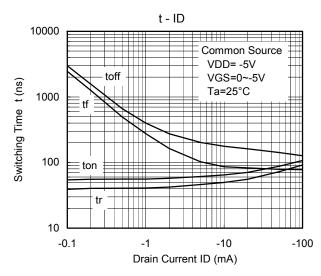


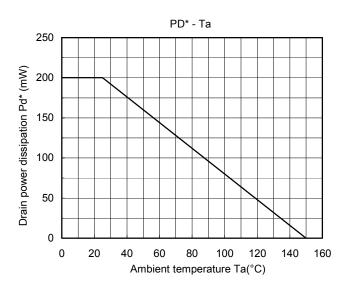












\*: Total Rating

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